### 4001

## 256 x 8 MASK PROGRAMMABLE ROM AND 4 BIT I/O PORT

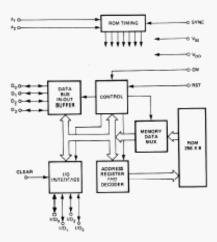
- Direct Interface to MCS-40™ 4 Bit Data Bus
- I/O Port Low-Power TTL Compatible
- 16 Pin Dual In-Line Package
- Standard Operating Temperature Range of 0° to 70°C
- Also Available With -40° to +85°C Operating Range

The 4001 performs two basic and distinct functions. As a ROM it stores 256 x 8 words of program or data tables; as a vehicle of communication with peripheral devices it is provided with 4 I/O pins and associated control logic to perform input and output operations. The 4001 is a PMOS device, compatible with all other MCS-40" devices.

### PIN CONFIGURATION



### BLOCK DIAGRAM



#### 4001

| Pin Description |  |  |  |  |
|-----------------|--|--|--|--|
| Pin No.         | Designation/<br>Type of Logic            | Description of Function  |  |  |
| 1-4             | D <sub>0</sub> ·D <sub>3</sub> /Neg.     | Bidirectional data bus. All ad-<br>dress and data communication<br>between the processor and<br>ROM is handled by these lines.   |  |  |
| 5               | V <sub>SS</sub>                          | Most positive supply voltage.  |  |  |
| 6-7             | ¢1, ¢2/Neg.                              | Non-overlapped clock signals which determine device timing   |  |  |
| 8               | SYNC/Neg.                                | System synchronization signal<br>generated by processor.   |  |  |
| 9               | RESET/Neg.                               | Reset input. A negative level (V <sub>DD</sub> ) on this pin will clear in ternal flip-flops and buffers. The input buffers are not cleared by this signal.                    |  |  |
| 10              | CL/Neg.                                  | Clear input for I/O lines. A neg-<br>ative level on this pin will clear<br>the I/O buffers. This pin may<br>be driven by a TTL output and<br>a 1K pull-up to V <sub>SS</sub> . |  |  |
| 11              | CM-ROM/Neg.                              | Chip enable generated by the processor.  |  |  |
| 12              | $v_{DD}$                                 | Main supply voltage value. Must<br>be V <sub>SS</sub> = 15.0V ±5%.   |  |  |
| 13-16           | I/O <sub>0</sub> ·I/O <sub>3</sub> /Neg. | A single I/O port consisting of<br>4 bidirectional and selectable<br>lines.  |  |  |
|                 |  |  |  |  |

### **Functional Description**

Address and data are transferred in and out by time multiplexing on 4 data bus lines. Timing is internally generated using two clock signals,  $\phi_1$  and  $\phi_2$ , and a SYNC signal supplied by the CPU. Addresses are received from the CPU on three time periods following SYNC, and select 1 out of 256 words and 1 out of 16 ROM's. For that purpose, each ROM is identified as  $\pm 0$ , 1, 2, through 15, by metal cotion. A Command ROM Line (CM-ROM) is also provided and it is used to select a ROM bank (group of 16 ROM's).

During the two time periods of the instruction cycle  $(M_1)$  &  $M_2$ I following the addressing time, information is transferred from the ROM to the data bus lines.

A second mode of operation of the ROM is as an Input/ Output control device. In that mode a ROM chip will route information to and from data bus lines in and out of 4 I/O external lines. Each chip has the capability to identify itself for an I/O port operation, recognize an I/O port instruction and decide whether it is an Input or an Output operation and execute the instruction. An external signal ICLI will asynchronously clear the output register during normal operation.

All internal flip flops (including the output register) will be reset when the RESET line goes low (V<sub>DD</sub>).

### I/O Options

Each I/O pin on each ROM can be uniquely chosen to be either an input or output line by metal option. Also each input or output can either be inverted or direct. When the pin is chosen as an input it may have an on-chip resistor connected to either V<sub>DD</sub> or V<sub>SS</sub>.

#### Instruction Execution

The 4001 responds to the following instructions.

### 1. SRC Instruction (Send address to ROM and RAM)

When the CPU executes an SRC instruction it will send out 8 bits of data during X<sub>2</sub> and X<sub>3</sub> and will activate the CM-ROM and one CM-RAM line at X<sub>2</sub>. Data at X<sub>2</sub>, (representing the contents of the first register of the register pair addressed by the SRC instruction) with simultaneous presence of CM-ROM, is interpreted by the 4001 as the chip number of the unit that should later perform an I/O operation. Data at X<sub>3</sub> is ignored.

### 2. WRR - Write ROM Port

The content of the accumulator is transferred to the ROM output port of the previously selected ROM oith. The data is available on the output pins until a new WRR is executed on the same chip. The ACC content and carry/link are unaffected, IThe LSB bit of the accumulator appears on I/O<sub>D</sub>.) No operation is performed on I/O lines coded as inputs.

### 3. RDR - Read ROM Port

The data present at the input lines of the previously selected ROM chip is transferred to the accumulator.

If the I/O option has both inputs and outputs within the same 4 I/O lines, the user can choose to have either "0" transferred to the accumulator for those I/O pins coded as outputs, when an RDR instruction is executed. For example, given a port with the I/O lines coded with 2 inputs and 2 outputs, when RDR is executed, the transfer is as shown below:

### **Timing Consideration**

In the ROM mode of operation the 4001 will receive an 8 bit address during  $A_1$  and  $A_2$  times of the instruction cycle and a chip number, together with CM-ROM, during  $A_3$  time. When CM-ROM is present, only the chip whose metal option code matches the chip number code sent during  $A_3$  is allowed to send data our during the following two cycles:  $M_1$  and  $M_2$ . The activity of the 4001 in the ROM mode ends at  $M_2$ .

In the I/O mode of operation, the selected 4001 (by SRC) after receiving RDR will transfer the information present at its I/O pins to the data bus at X2. If the instruction received was WRR, the data present on the data bus at X2.92 will be latched on the output flip-flops associated with the I/O lines.

### Ordering Information

When ordering a 4001, the following information must be specified:

- Chip number
- 2. All the metal options for each I/O pin.
- ROM pattern to be stored in each of the 256

A blank customer truth table is available upon request from Intel. A copy of this table is shown and blank copy can be found following the detailed 4001 characteristics.

EXAMPLES - DESIRED OPTION/CONNECTIONS RE-QUIRED

- 1. Non-inverting output (negative logic output) 1 and 3 are connected.
- 2 Inverting output (positive logic output) 1 and 4 are connected.
- Non-inverting input (no input resistor negative logic input) - only 5 is connected.
- Inverting input (input resistor to V<sub>SS</sub> positive logic input) - 2, 6, 7, and 9 are connected.
- 5. Non-inverting input (input resistor to V<sub>DO</sub> negative logic input) - 2, 7, 8, and 10 are connected.
- 6. If inputs and outputs are mixed on the same port, the pins used as the outputs must have the internal resistor connected to either VDD or VSS (8 and 9 or 8 and 10 must be connected). This is necessary for testing purposes. For example, if there are two inverting inputs (with no input resistor) and 2 non-inverting outputs the

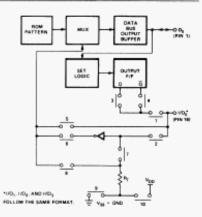
connection would be made as follows:

Inputs - 2 and 6 are connected Outputs - 1, 3, 8 and 9 are connected or 1. 3. 8 and 10 are connected

If the pins on a port are all inputs or all outputs, the internal resistors do not have to be connected.

It should be noted that all internal logic and processing is performed in negative logic, i.e., "1" equals VDD and "D" equals VSS. For positive logic conversion, the inverted options should be selected.

TTL compatibility is obtained by VDD = -10V ±5% and VSS = 5V ± 5%. An external 12K resistor should be used on all outputs to insure the logic "0" state (VOL).



4001 Available Metal Option for Each I/O Pin.

### Absolute Maximum Ratings\*

| Ambient Temperature Under Bias 0°C to 70°C | "COMMENT:  |
|--|--|
| Storage Temperature65°C to + 125°C         | Stresses above those listed a                                  |
| Input Voltages and Supply Voltage          | They cause permanent demag                                     |
| with respect to Vss                        | only and functional operation<br>conditions above those indica |
| Power Dissipation                          | apec/Vestion is not impred.                                    |

Streams above those tated under "Absorute Maximum Watings" They cause permanent demage to the device. This is a stress rating only and functional operation of the device at mase or any other conditions above those indicated in the operational sections of this

#### 4001

### **D.C. and Operating Characteristics**

TA = 0°C to 70°C; VSS = VDO = 15V ±5%; t<sub>aPM</sub> = t<sub>aD1</sub> = 400 nsec; t<sub>aD2</sub> = 150 nsec; Logic "0" is defined as the more positive voltage (VIH, VOH): Logic "1" is defined as the more negative voltage (VIL, VOL); Unless Otherwise Specified.

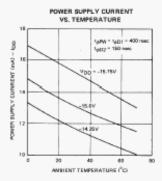
#### SUPPLY CURRENT

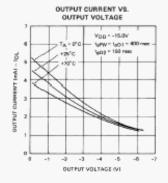
| Symbol              | Parameter                               | Min.                 | Limit<br>Typ. | Max.                 | Unit | Test Conditions   |
|---------------------|---|----------------------|---------------|----------------------|------|---|
| l <sub>DO</sub>     | Average Supply Current                  |                      | 15            | 30                   | mA   | T <sub>A</sub> = 25°C   |
| NPUT CH             | ARACTERISTICS - ALL INPUTS EXCEPT I/O P | INS                  |               |                      |      |   |
| Iu .                | Input Leakage Current                   |                      |               | 10                   | μA   | VIL = VDD   |
| VIH                 | Input High Voltage (Except Clocks)      | V <sub>58</sub> -1.5 |               | V <sub>55</sub> +.3  | ٧    |   |
| V <sub>IL</sub>     | Input Low Voltage (Except Clocks)       | V <sub>DD</sub>      |               | V <sub>58</sub> -5.5 | ٧    |   |
| ViHC                | Input High Voltage Clocks               | V <sub>SS</sub> -1.5 |               | V <sub>SS</sub> +.3  | ٧    |   |
| VILC                | Input Low Voltage Clocks                | V <sub>DD</sub>      |               | Vss-13.4             | ٧    |   |
| DUTPUT (            | CHARACTERISTICS - ALL OUTPUTS EXCEPT    | I/O PINS             |               |                      |      |   |
| lo                  | Data Bus Output Leakage Current         |                      |               | 10                   | μΑ   | V <sub>OUT</sub> = -12V   |
| VoH                 | Output High Voltage                     | V <sub>88</sub> 5V   | Vss           |                      | V    | Capacitive Load   |
| loc .               | Data Lines Sinking Current              | 8                    | 15            |                      | mA   | Vout = Vss  |
| V <sub>OL</sub>     | Output Low Voltage, Date Bus, CM, SYNC  | V <sub>88-12</sub>   |               | V <sub>SS</sub> -6.5 | V    | I <sub>OL</sub> = 0.5mA   |
| ROH                 | Output Resistance, Data Line "0" Level  |                      | 150           | 250                  | Ω    | V <sub>OUT</sub> = V <sub>SS</sub> 5V   |
| /O INPUT            | CHARACTERISTICS                         |                      |               |                      |      |   |
| ILI                 | Input Leakage Current                   |                      |               | 10                   | μA   |   |
| VIH                 | Input High Voltage                      | V <sub>88</sub> =1.5 |               | V <sub>88</sub> +.3  | ٧    |   |
| VIL                 | Input Low Voltage, Inverting Input      | Voo                  |               | V <sub>SS</sub> -4.2 | ٧    |   |
| VIL                 | Input Low Voltage, Non-inverting Input  | V <sub>DO</sub>      |               | V <sub>88</sub> -6.5 | V.   |   |
| VIL                 | CL Input Low Voltage                    | Voo                  |               | V <sub>SS</sub> -4.2 | ٧    |   |
| Rį                  | Input Resistance, if Used               | 10                   | 18            | 35                   | kΩ   | R <sub>1</sub> tied to V <sub>SS</sub> ;<br>V <sub>IN</sub> = V <sub>SS</sub> -3V |
| B <sub>1</sub> [1]  | Input Resistance, if Used               | 15                   | 26            | 40                   | kΩ   | R <sub>1</sub> tied to V <sub>DD</sub> ;<br>V <sub>IN</sub> = V <sub>SS</sub> -3V |
| /O OUTP             | UT CHARACTERISTICS                      |                      |               |                      |      |   |
| Voн                 | Output High Voltage                     | V <sub>88</sub> 5V   |               |                      | V    | 1 <sub>DUT</sub> = 0  |
| RoH                 | I/O Output "O" Resistance               |                      | 1.2           | 2                    | kΩ   | V <sub>OUT</sub> = V <sub>SS</sub> 5V   |
| loL                 | I/O Output "1" Sink Current             | 2.5                  | 5             |                      | mA.  | V <sub>OUT</sub> = V <sub>SS</sub> 5V   |
| lo <sub>L</sub> (2) | I/O Output "1" Sink Current             | 0.8                  | 3             |                      | mÀ   | Vout = Vss -4.85V   |
| VOL                 | I/O Output Low Voltage                  | V <sub>SS</sub> -12  |               | V <sub>SS</sub> -6.5 | ٧    | I <sub>OUT</sub> = 50μA   |
| CAPACIT             | ANCE                                    |                      |               |                      |      |   |
| Cø                  | Clock Capacitance                       |                      | 8             | 15                   | pF   | VIN = VSS   |
| Сов                 | Deta Bus Capacitance                    |                      | 9.5           | 15                   | pF   | V <sub>IN</sub> = V <sub>SS</sub>   |
| CIN                 | Input Capacitance                       |                      |               | 10                   | ρF   | V <sub>IN</sub> = V <sub>SS</sub>   |
| Cour                | Output Capacitance                      |                      |               | 10                   | pF   | V <sub>IN</sub> - V <sub>SS</sub>   |

Notes: 1. R<sub>I</sub> is large signal equivalent resistance to (Vgg-12) V.

2. For TTL compatibility, use 12kΩ externel resistor to VDD.

### Typical D.C. Characteristics





### A.C. Characteristics TA = 0°C to 70°C, VSS -VDD = 15V ±5%

| Symbol               | Parameter  | Min. | Limit<br>Typ. | Max.                     | Unit           | Conditions  |
|----------------------|--|------|---------------|--------------------------|----------------|---|
| tev                  | Clock Period                                       | 1.35 |               | 2.0                      | Дзес           |   |
| tøg                  | Clock Rise Time                                    |      |               | 50                       | 116            |   |
| t#F                  | Clock Fall Times                                   |      |               | 50                       | ns             |   |
| tdew                 | Clock Width  | 380  |               | 480                      | ns             |   |
| t#D1                 | Clock Delay $\phi_1$ to $\phi_2$                   | 400  |               | 550                      | ns             |   |
| t#p2                 | Clock Delay $\phi_2$ to $\phi_1$                   | 150  |               |                          | ns             |   |
| t <sub>W</sub>       | Data-In, CM, SYNC Write Time                       | 350  | 100           |                          | ns             |   |
| t <sub>H</sub> [1,3] | Data-In, CM, SYNC Hold Time                        | 40   | 20            |                          | ns             |   |
| t <sub>O8</sub> [2]  | Set Time (Reference)                               | 0    |               |                          | ns             |   |
| <sup>†</sup> ACC     | Data-Out Access Time Data Lines SYNC CM-ROM CM-RAM |      |               | 930<br>930<br>930<br>930 | ns<br>ns<br>ns | COUT =<br>500pF Data Lines<br>500pF SYNC<br>160pF CM-ROM<br>50pF CM-RAM |
| t <sub>OH</sub>      | Data-Out Hold Time                                 | 50   | 150           |                          | ns             | C <sub>OUT</sub> = 20pF   |
| t <sub>IS</sub>      | I/O Input Set-Time                                 | 50   |               |                          | ns.            |   |
| T <sub>EH</sub>      | I/O Input Hold-Time                                | 100  |               |                          | ns             |   |
| t <sub>O</sub>       | I/O Output Delay                                   |      |               | 1500                     | ns             | C <sub>DUT</sub> = 100pF  |
| t <sub>C</sub> [4]   | I/O Output Lines Delay on Clear                    |      |               | 1500                     | ns             | C <sub>OUT</sub> = 100pF  |

Note: 1. Typ measured with typt = 10mset.

2. Type: Is Doss Bus, SYNC and CM-line output access time referred to the dry trailing edge which clocks these lines out. typ is the same output access time referred to the leading edge of the next dry clock pulse.

3. All MCS-80 components which may transmit instruction or data to 4004/4040 at Mry and Xy elways enter a floot state until the 4004/4040 at second the same over the data bus at X<sub>3</sub> and X<sub>3</sub> time. Therefore the typ requirement is always insured since each component contributes 10aA of leakage current and 10pF of capacitance which guarantees that the data bus cannot change faster than TV/as.

4. CL on the 4001 is used to asynchronously clear the output filip-flops associated with the I/D lines.

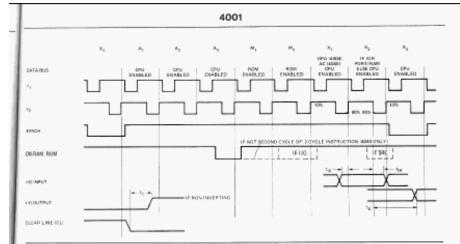


Figure 1. Timing Diagram

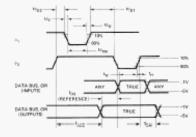


Figure 2. Timing Detail

To insure optimum handling of ROM programs and avoid delays, programs should be specified in the following format.

### Paper Tape Format\*

A 1" wide paper tape using 8 bit ASCH code, such as a model 33ASR teletype produces:

#### A. Preamble

- Preceding the first word field and following the last word field, there should be a leader/trailer length of at least 25 characters. This should consist of rubout purches.
- Included in the tape before the leader, and preceded by another leader, should be the customer's complete telex or two number and if more than one pattern is being transmitted, the ROM pattern number.
- The first ROM pattern preamble field is the device type number or ROM number. The field should be framed by an "I" and "-"

14001-

This should be followed by the chip select information encoded in decimal (two digits), and enclosed by "C" and "S", as in

"ChhS"

The valid select digits for the 4001 are 0–15 "COS" = "C155"

Finally, the I/O options would be specified on a port by-port basis with the connections to be made separated by commas, and enclosed in parenthese:

where (n1, n2 . . .) are the option numbers assoclated with one //O line. Hence, for a 4001 there will be four bracketed collections of I/O options. Each I/O pin has a series of 10 possible connections. These connections are consecutively numbered from 1-10. It is these numbers that should be in parentheses for each I/O pin.

Example: "1 )" indicates no connection
"1 1 1" indicates only #1
"(2,5,7)" indicates connections
#2, 5 and 7.

I/O options should be placed on the tape sequentially for the 4001 from I/O0-I/O3(4), Always avoid illegal combinations.

\*NOTE: Cards may also be submitted.

#### B. ROM Code

The format requirements are as follows:

- All word fields are to be punched in consecutive order, starting with word field 0 (all addresses low). There must be exactly N word fields for the N x 8 ROM organization.
- Each word field must begin with the start character B and end with the stop character F. There must be exactly 8 data characters between the B and F. Within the word field, a Presults in a high lervel output (V<sub>SS</sub> or logic 0 for MCS-40 CPUs) and a Nresults in a low level output (V<sub>DD</sub> or logic I for MCS-40 CPUs).

Example of 256 x 8 format (N=256):



- 3. Between word fields, comments not containing B's or F's may be inserted. Carriage return and time feed characters should be inserted (as a "comment") just before each word field (or at least between every four word fields). When these carriage returns, etc., are inserted, the tape may be easily listed on the teletype for purposes, of error checking. It may be helpful to insert the word number (as a comment) at least every four word fields.
- 4. Within the RDM pattern words a character, "X", may be used. Where "P" and "N" indicate a "0" and "1" setting respectively, an "X" will indicate a single bit "Doo"! Care" setting. This allows the optimum default bit values to be selected by Intel. The bit value will be fixed to allow for testing. The values will be specified to the user on the Verification Listing tape.

In the place of a standard BPNF word, a "B\*nF" word may be used. This indicates that the data in the last BPNF word encountered is to be repeated for the next in words (1  $\leq$  n  $\leq$  1023). More that if a repeat count of 4 is given in word position 10, then words 10, 11, 12, and 13 will be repeats of word 9 (except for Don's Care bits which might conceivably have different assigned values).

To indicate that an entire block (such as the remainder of a ROM) is not used (i.e., Don't Care), a word of Don't Care data can be followed by the remaining word count in a repeat count form.



### MCS<sup>®</sup> CUSTOM ROM ORDER FORM

# 4001 ROM

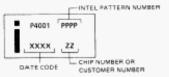
| CUSTOMER    |                    |  |  |  |
|-------------|--------------------|--|--|--|
| P.O. NUMBER |                    |  |  |  |
| DATE        |                    |  |  |  |
|             | For Intel use only |  |  |  |
| S#          | PPPP               |  |  |  |
| STD         | ZZ                 |  |  |  |
|             | DD                 |  |  |  |
| APP         | DATE               |  |  |  |

All custom 4001 ROM orders must be submitted on this form. Programming information should be sent in the form of computer punched cards or punched paper tage per the formats designated on this order form. Additional forms are evailable from Intel.

#### MARKING

The marking as shown at the right must contain the Intal logo, the product type (P4001), the 4-digit Intal pattern number (PPPP), a date code (XXXXX), and the 2-digit chip number IDD). An optional oustomer dentification number may be substituted for the chip number (ZZI, Optional Customer Number (maximum 6 characters or spaces).

CUSTOMER NUMBER \_\_\_\_\_



### MASK OPTION SPECIFICATIONS

8. I/O OPTION - Specify the connection numbers for each I/O pin (next page). Examples of some of the possible I/O options are shown below:

EXAMPLES - DESIRED OPTIONICON-NECTIONS REQUIRED

- Non-inverting output 1 and 3 are connected.
- Inverting output 1 and 4 are connected.
- Non-inverting input Ino input resistor! – only 5 is connected.
- Inverting input limput resistor to Vggl
   2, 6, 7, and 9 are connected.

- Non-inverting input (input resistor to VODI - 2, 7, 8, and 10 are con-
- 6. If imputs and outputs are mixed on the same port, the pins used at the outputs must have the internal realization connected to either Vojo or Vojo 18 and 9 or 8 and 10 must be connected. This is includely for Noticing purposes. For example, if there are the investing input field with no input resident and two non-inventing outputs, the connection would be made as follows:

Inputs - 2 and 6 are connected Outputs - 1, 3, 8, and 9 are con-

1, 3, 8, and 10 are connected

If the pine on a port are all inputs or all outputs, the internal resistors do not have to be connected. C. 4001 CUSTOM ROM PATTERN— Programming information should be sent in the form of computer punched cards or punched paper tape. In either case, a princout of the truth table must accompany the order. Based on the particular customer pattern, the characters should be written as a "P" for a high level output " Vgg (negative logic "O") or an "N" for a low level output " Vgg (negative logic "f").

Note that:

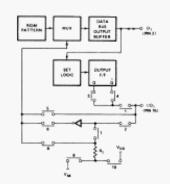
NOP = BPPPP PPPPF = 0000 0000

# 4001\_I/O Options

### 1/O<sub>0</sub> (PIN 16) CONNECTIONS DESIRED (LIST NUMBERS & CIRCLE

CONNECTIONS ON SCHEMATIC)\_

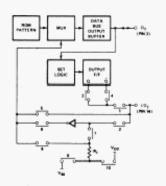
- a. For  $1^2L$  compared with a on the HO lines the scools indiseas should be  $V_{\rm SD}=-10V$  15%.  $V_{\rm SD}=-50$  15%. b. Hincommercing input option is used,  $V_{\rm L}=-6.5$  Voltaines muon that TTL).



# I/O, (PIN 15)

CONNECTIONS DESIRED (LIST NUMBERS & CIRCLE CONNECTIONS ON SCHEMATIC)...

- 4. For  $T^2L$  compared by on the  $\sqrt{U}$  has the supply violages should be  $V_{QQ} \approx -12^n e^{-1}h$ ,  $\log e^{-1}hh$ . By  $t^{-1}hh$  which is the standard for the order of the standard specific  $V_{QL} \approx -6.5$  from the standard from TTL1.

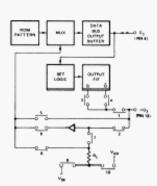


# 1/O2 (PIN 14)

CONNECTIONS DESIRED (LIST NUMBERS & CIRCLE CONNECTIONS ON SCHEMATIC)\_

- # For  $T^2L$  compatibility on the HD lines the supply voltages shows be  $V_{\rm DD} \approx -100$  with,  $V_{\rm BS} \approx +90^\circ$  e/H.

  B. If shows the integration of send,  $V_{\rm BS} \approx -6.5$  Voltains shown from TTU.)



# I/O<sub>3</sub> (PIN 13)

CONNECTIONS DESIRED ILIST NUMBERS & CIRCLE CONNECTIONS ON SCHEMATIC).

- a. For  $T^2$ s, interplat duting we the 11Q lines the sopply softeges the aid be  $V_{QQ} = -10V \cdot 5^4$ ,  $V_{QL} = -5V \cdot 25$ . by 11 near energy input sot on a wax,  $V_{QL} = -6.5$  Volta maximum inod TTs t